RoHS

HALOGEN

FREE

**Vishay Semiconductors** 

# Hyperfast Rectifier, 12 A FRED Pt<sup>®</sup> G5



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TO-220 FullPAK 2L

### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	12 A					
V <sub>R</sub>	600 V					
V <sub>F</sub> at I <sub>F</sub> at 125 °C	1.75 V					
t <sub>rr</sub> (typ.)	16 ns					
T <sub>J</sub> max.	175 °C					
Package	TO-220 FullPAK 2L					
Circuit configuration	Single					

### **FEATURES**

- Best in class forward voltage drop and switching losses trade off
- · Optimized for high speed operation
- COMPLIANT 175 °C maximum operating junction temperature
- Polyimide passivation
- Fully isolated package (V<sub>INS</sub> =2500 V<sub>RMS</sub>)
- True 2 pin package
- Designed and qualified according to JEDEC® JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **DESCRIPTION / APPLICATIONS**

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve as output rectifier for DC/DC stage in resonant converters and as PFC rectifier for aircon and industrial power supplies.

### **MECHANICAL DATA**

Case: TO-220 FullPAK 2L

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Repetitive peak reverse voltage	V <sub>RRM</sub>		600	V		
Average rectified forward current in DC	I <sub>F(AV)</sub>	T <sub>C</sub> = 100 °C, DC	12	٨		
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_C = 25 \text{ °C}, t_p = 10 \text{ ms}, \text{ sine wave}$	110	A		
Operating junction and storage temperature	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-		
Forward voltage	VF	I <sub>F</sub> = 12 A	-	2.35	3.35	V	
	۷F	I <sub>F</sub> = 12 A, T <sub>J</sub> = 125 °C	-	1.75	-		
Povereo lookago ourrent	1	$V_{R} = V_{R}$ rated	-	-	10		
Reverse leakage current	IR	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA	
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	10	-	pF	
Series inductance	L <sub>S</sub>	Measured to lead 5 mm from package body	-	8	-	nH	

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 \text{ A,d}I_F/c$	lt = 100 A/µs, V <sub>R</sub> = 30 V	-	16	-		
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	25	-	ns	
		T <sub>J</sub> = 125 °C		-	30	-		
Peak recovery current		$T_J = 25 \text{ °C}$ $I_F = 8 \text{ A}$		-	7.5	-	A	
Feak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	dl <sub>F</sub> /dt = 1000 A/µs V <sub>R</sub> = 400 V	-	13	-		
Poverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	75	-	nC	
Reverse recovery charge		T <sub>J</sub> = 125 °C		-	225	-		
Reverse recovery time	+	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 12 A dI <sub>F</sub> /dt = 1000 A/μs V <sub>B</sub> = 400 V	-	26	-	ns	
Reverse recovery lime	t <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	32	-	115	
Pool recovery ourrent		T <sub>J</sub> = 25 °C		-	9	-	A	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		-	14	-		
Reverse recovery charge	0	T <sub>J</sub> = 25 °C		-	90	-	-	
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	275	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Thermal resistance, junction-to-case	R <sub>thJC</sub>		-	-	3.5	°C/W	
Weight			-	2.0	-	g	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C	
Marking device		Case style TO-220 FullPAK 2L	E5TW1206FP				

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**VS-E5TW1206FP-N3** 

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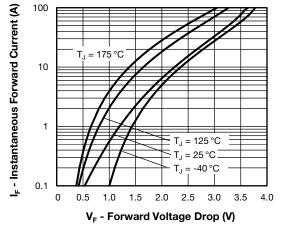


Fig. 1 - Forward Voltage Drop Characteristics

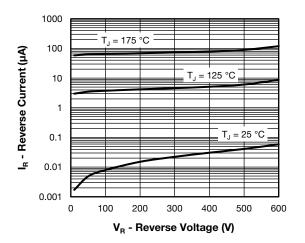


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

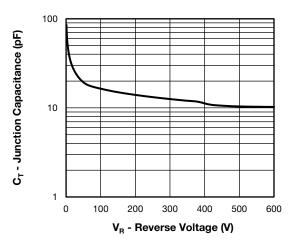


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

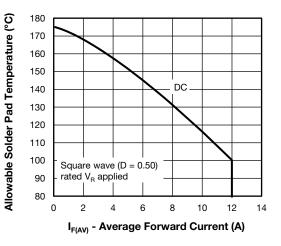


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

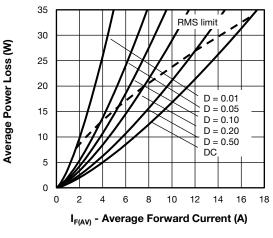


Fig. 5 - Forward Power Loss Characteristics

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## VS-E5TW1206FP-N3

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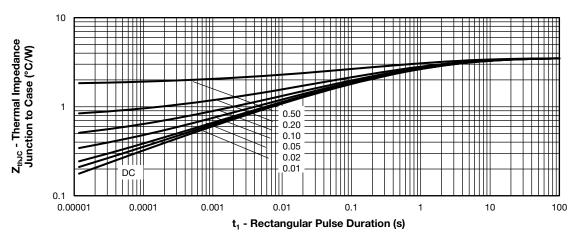
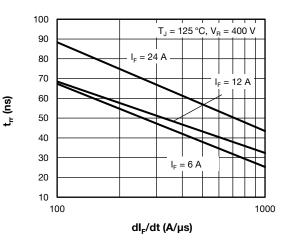


Fig. 6 - Transient Thermal Impedance, Junction to Case



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Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

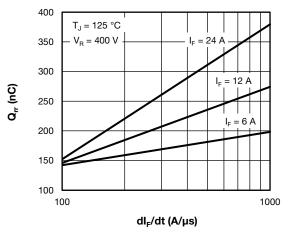


Fig. 8 - Typical Reverse Recovery Charge vs. dl<sub>F</sub>/dt

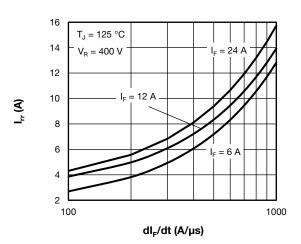


Fig. 9 - Typical Reverse Recovery Current vs. dl<sub>F</sub>/dt

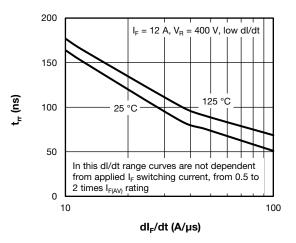


Fig. 10 - Typical Reverse Recovery Time vs. dI<sub>F</sub>/dt

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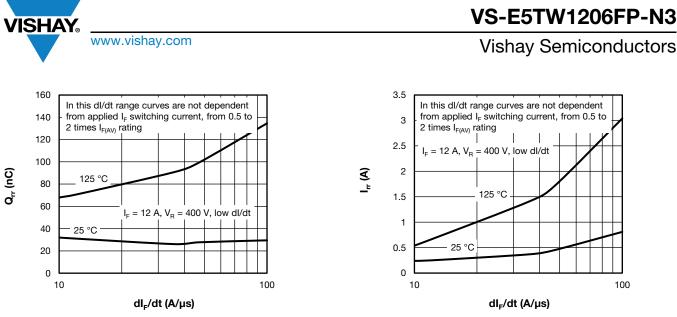


Fig. 11 - Typical Reverse Recovery Charge vs. dl<sub>F</sub>/dt



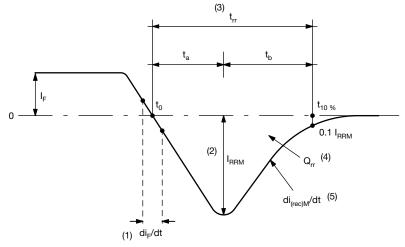


Fig. 13 - Reverse Recovery Waveform and Definitions

#### Notes

- <sup>(1)</sup> di<sub>F</sub>/dt rate of change of current through zero crossing
- $^{(2)}\ \ I_{RRM}$  peak reverse recovery current
- $^{(3)}$  t<sub>rr</sub> reverse recovery time measured from t<sub>0</sub>, crossing point of negative going I<sub>F</sub>, to point t<sub>10%</sub>, 0.1 I<sub>RRM</sub>
- $^{(4)}$   $Q_{rr}$  area under curve defined by  $t_0$  and  $t_{10\ \%}$

t<sub>10 %</sub>

$$Q_{rr} = \int_{t_0} I(t)dt$$

 $^{(5)}$  di<sub>(rec)</sub>M/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>



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#### **ORDERING INFORMATION TABLE**

Device code	VS-	E	5	т	w	12	06	FP	-N3
	1	2	3	4	5	6	7	8	9
	1 -	Visł	nay Sem	niconduc	ctors pro	oduct			
	2 -	E =	single c	diode					
	3 -	5 =	FRED g	eneratio	on 5				
	4 -		kage:						
	<u>4</u>			packag					
	5 -	W =	W = warp hyperfast recovery						
	6 -	Cur	Current rating $(12 = 12 \text{ A})$						
	7 -	Volt	Voltage rating (06 = 600 V)						
	8 -	FP	= TO-22	20 FullP	AK 2L				
	9 -	Env	ironmer	ntal digit	:				
		N3	= halog	en-free,	RoHS-o	complia	nt, and	totally I	ead (Pb)

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-E5TW1206FP-N3	50	1000	Antistatic plastic tube			

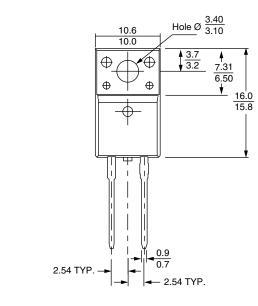
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96157				
Part marking information	www.vishay.com/doc?95392				

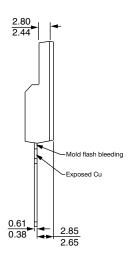


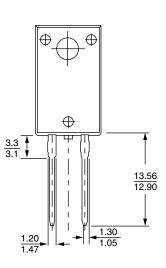
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# 2L TO-220 FullPAK

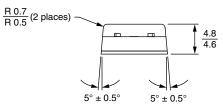
#### **DIMENSIONS** in millimeters







Bottom view





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